71V416L12YG8 Details PDF





71V416L12YG8

Part Number:	71V416L12YG8
Manufacturer/Brand:	IDT (Integrated Device Technology)
Product description	IC SRAM 4M PARALLEL 44SOJ
Datasheets:	m 71V416L12YG8.pdf
RoHs Status	Lead free / RoHS Compliant
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

Image may be representation. See specifications for product details.

REQUEST FOR QUOTATION

Specifications of 71V416L12YG8

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	LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant	
IDT71V416	DETAILED DESCRIPTION	SRAM - Asynchronous Memory IC 4Mb (25	ъ́К x 16) Paralle
	BASE PART NUMBER	IDT71V416	
CCESS TIME 12ns	ACCESS TIME	12ns	

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